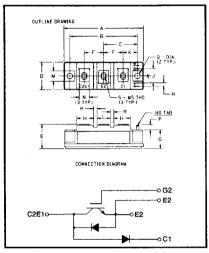
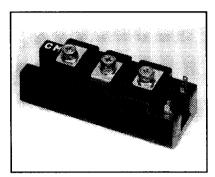


## Chopper IGBTMOD™ E-Series Module 50 Amperes/1200 Volts



CM50E3Y-24E Outline Drawing

| Dimensions | Inches     | Millimeters |  |  |  |  |
|------------|------------|-------------|--|--|--|--|
| Α          | 3.70       | 94.0        |  |  |  |  |
| В          | 3.150±0.01 | 80.0±0.25   |  |  |  |  |
| С          | 1.57       | 40.0        |  |  |  |  |
| D          | 1.34       | 34.0        |  |  |  |  |
| E          | 1.22 Max.  | 31.0 Max.   |  |  |  |  |
| F          | 0.90       | 23.0        |  |  |  |  |
| G          | 0.85       | 21.5        |  |  |  |  |
| <u>H</u>   | 0.79       | 20.0        |  |  |  |  |
| J          | 0.71       | 18.0        |  |  |  |  |
| K          | 0.67       | 17.0        |  |  |  |  |
| L          | 0.63       | 16.0        |  |  |  |  |
| М          | 0.51       | 13.0        |  |  |  |  |
| N          | 0.47       | 12.0        |  |  |  |  |
| P          | 0.28       | 7.0         |  |  |  |  |
| Q          | 0.265 Dia. | Dia. 6.5    |  |  |  |  |
| R          | 0.16       | 4.0         |  |  |  |  |
| S          | M5 Metric  | M5          |  |  |  |  |



CM50E3Y-24E Chopper IGBTMOD™ E-Series Module 50 Amperes/1200 Volts

#### Description:

Powerex Chopper IGBTMOD<sup>TM</sup> Modules are designed for use in switching applications. Each module consists of one IGBT Transistor having a reverse-connected super-fast recovery free-wheel diode and an anode-collector connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

| Fea | atures:<br>Low Drive Power                            |
|-----|---|
|     | Low V <sub>CE(sat)</sub>                              |
|     | Discrete Super-Fast Recovery (150ns) Free-Wheel Diode |
|     | High Frequency Operation (15-20kHz)                   |
|     | Isolated Baseplate for Easy<br>Heat Sinking           |
| Аp  | plications:   |
|     | DC Motor Control<br>Boost Regulator                   |
|     | dering Information:<br>ample: Select the complete par |

module number you desire from

1200V (V<sub>CES</sub>), 50 Ampere Chopper IGBTMOD™ Power

the table below

Module.

-i.e. CM50E3Y-24E is a

| Туре | Current Rating<br>Amperes | V <sub>CES</sub><br>Volts (x 50) |
|------|---------------------------|----------------------------------|
| СМ   | 50                        | 24                               |



CM50E3Y-24E Chopper IGBTMOD™ E-Series Module 50 Amperes/1200 Volts

## Absolute Maximum Ratings, T<sub>i</sub>= 25 °C unless otherwise specified

| Ratings                                 | Symbol           | CM50E3Y-24E | Units   |
|---|------------------|-------------|---------|
| Junction Temperature                    | T <sub>i</sub>   | -40 to 150  | °C      |
| Storage Temperature                     | T <sub>stg</sub> | 40 to 125   | °C      |
| Collector-Emitter Voltage (G-E SHORT)   | V <sub>CES</sub> | 1200        | Volts   |
| Gate-Emitter Voltage                    | V <sub>GES</sub> | ±20         | Volts   |
| Collector Current                       | I <sub>C</sub>   | 50          | Amperes |
| Peak Collector Current                  | I <sub>CM</sub>  | 100*        | Amperes |
| Diode Forward Current                   | I <sub>FM</sub>  | 50          | Amperes |
| Diode Forward Surge Current             | I <sub>FM</sub>  | 100*        | Amperes |
| Power Dissipation                       | P <sub>d</sub>   | 400         | Watts   |
| Max. Mounting Torque M5 Terminal Screws | _                | 17          | in-lb   |
| Max. Mounting Torque M6 Mounting Screws | _                | 26          | in-lb   |
| Module Weight (Typical)                 | _                | 190         | Grams   |
| V Isolation                             | V <sub>RMS</sub> | 2500        | Volts   |

<sup>\*</sup> Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

## Static Electrical Characteristics, $T_i$ = 25 °C unless otherwise specified

| Characteristics                      | Symbol               | Test Conditions   | Min. | Тур. | Max.  | Units |
|--------------------------------------|----------------------|---|------|------|-------|-------|
| Collector-Cutoff Current             | I <sub>CES</sub>     | V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0V           |      | _    | 1.0   | mA    |
| Gate Leakage Current                 | I <sub>GES</sub>     | $V_{GE} = V_{GES}, V_{CE} = 0V$                                     | -    | -    | 0.5   | μΑ    |
| Gate-Emitter Threshold Voltage       | V <sub>GE(th)</sub>  | I <sub>C</sub> = 5mA, V <sub>CE</sub> = 10V                         | 3.5  | 5.0  | 6.5   | Volts |
| Collector-Emitter Saturation Voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> = 50A, V <sub>GE</sub> = 15V                         |      | _    | 4.0** | Volts |
|                                      | ` '                  | I <sub>C</sub> = 50A, V <sub>GE</sub> = 15V, T <sub>i</sub> = 150°C | _    | _    | 4.0** | Volts |
| Total Gate Charge                    | Q <sub>G</sub>       | V <sub>CC</sub> = 600V, I <sub>C</sub> = 50A, V <sub>GS</sub> = 15V |      | 530  | _     | nC    |
| Diode Forward Voltage                | V <sub>FM</sub>      | $I_{E} = 50A, V_{GE} = 0V$  | _    | -    | 2.5   | Volts |

<sup>\*\*</sup> Pulse width and repetition rate should be such that device junction temperature rise is negligible.

# Dynamic Electrical Characteristics, $T_i = 25$ °C unless otherwise specified

| Characteristics   |                     | Symbol              | Test Conditions  | Min. | Тур. | Max. | Units |
|---|---------------------|---------------------|--|------|------|------|-------|
| Input Capacitance   | C <sub>ies</sub>    |                     | _  |      | 20   | nF   |       |
| Output Capacita   | ance                |                     | $V_{GE} = 0V, V_{CE} = 10V, f = 1MHz$                                      | _    |      | 6    | nF    |
| Reverse Transf  | fer Capacitance     | C <sub>res</sub>    | <del>_</del>   | -    | -    | 4    | nF    |
| Resistive<br>Load<br>Switch Times                         | Turn-on Delay Time  | t <sub>d(on)</sub>  | $V_{CC} = 600V, I_{C} = 50A,$ $V_{GE1} = V_{GE2} = 15V, R_{G} = 6.3\Omega$ | -    | _    | 100  | ns    |
|   | Rise Time           | ţ,                  |  | _    | _    | 200  | ns    |
|   | Turn-off Delay Time | t <sub>d(off)</sub> |  | _    | -    | 200  | ns    |
|   | Fall Time           | t <sub>t</sub>      |  | _    | _    | 400  | ns    |
| Diode Reverse Recovery Time Diode Reverse Recovery Charge |                     | t <sub>rr</sub>     | $I_E = 50A$ , $di_E/dt = -100A/\mu s$                                      |      | _    | 300  | ns    |
|   |                     | Q <sub>rr</sub>     | $I_E = 50A$ , $di_E/dt = -100A/\mu s$                                      |      | 1.1  |      | μC    |

# Thermal and Mechanical Characteristics, $T_i = 25$ °C unless otherwise specified

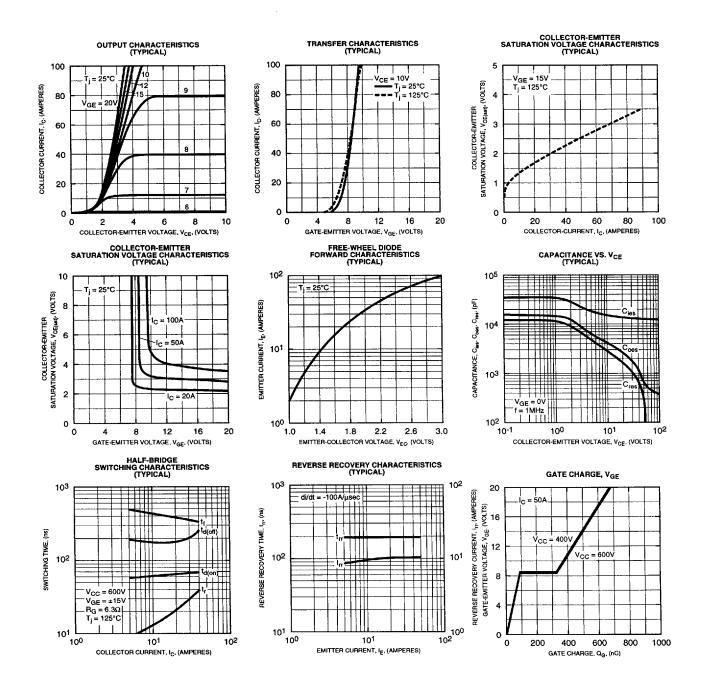
| Characteristics                      | Symbol               | Test Conditions      | Min.         | Typ. | Max. | Units |
|--------------------------------------|----------------------|----------------------|--------------|------|------|-------|
| Thermal Resistance, Junction to Case | R <sub>th(j-c)</sub> | Per IGBT             | <del>-</del> | _    | 0.31 | °C/W  |
| Thermal Resistance, Junction to Case | R <sub>th(j-c)</sub> | Per Free Wheel Diode | -            | _    | 0.70 | °C/W  |
| Contact Thermal Resistance           | R <sub>th(c-f)</sub> | Per Half Module      | _            | -    | 0.15 | °C/W  |

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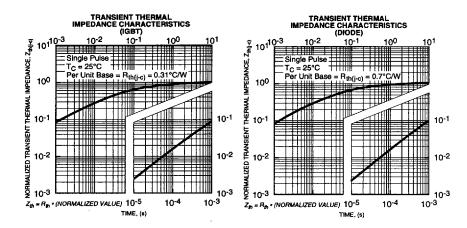


CM50E3Y-24E Chopper IGBTMOD™ E-Series Module 50 Amperes/1200 Volts

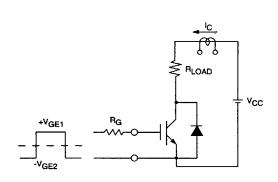


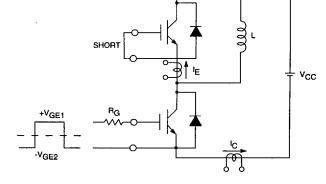


CM50E3Y-24E Chopper IGBTMOD™ E-Series Module 50 Amperes/1200 Volts



### **SWITCHING TIME TEST CIRCUITS & WAVEFORMS**

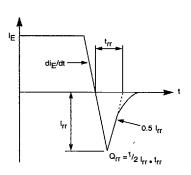




#### RESISTANCE LOAD SWITCHING TEST CIRCUIT

VGE 90% t

HALF-BRIDGE SWITCHING TEST CIRCUIT



trr, Qrr WAVEFORMS

SWITCHING TIME TEST WAVEFORMS

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